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## Synthesis and characterization of La<sub>2</sub>NiO<sub>4+ $\delta$ </sub> coatings deposited by reactive magnetron sputtering using plasma emission monitoring

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#### ABSTRACT

This work focuses on the structural and electrical characterization of La–Ni–O coatings deposited by reactive magnetron sputtering using Plasma Emission Monitoring (PEM) which allows high deposition rate. The optimal regulation setpoint for lanthanum deposition is determined and then the current dissipated on the nickel target is adjusted to obtain the convenient La/Ni ratio to achieve the  $K_2NiF_4$  structure. After an appropriate annealing treatment, all coatings exhibit crystalline structures that depend on the La/Ni ratio. Some cracks appear on samples deposited on alumina substrates depending to the argon flow rate and influence their electrical behavior.

Keywords: La<sub>2</sub>NiO<sub>4</sub> Reactive magnetron sputtering Plasma emission monitoring Structural investigation Electrical properties

#### 1. Introduction

It is well known that the short life time and the high cost of the components of nowadays Solid Oxide Fuel Cells (SOFC) are induced by their high operating temperature (1273 K). The challenge, that many researches try to face with, is to reduce this operating temperature below 1073 K while maintaining the fuel cell performances (IT-SOFC). However at low operating temperature, the electrocatalytic activity of the standard cathode (lanthanum strontium oxide such as LSM: La<sub>1 - x</sub>Sr<sub>x</sub>MnO<sub>3</sub>) decreases, leading to high overpotential and reduced power density. These lanthanum strontium oxides have also been involved in the formation of secondary phases at the interface with the YSZ electrolyte (La<sub>2</sub>Zr<sub>2</sub>O<sub>7</sub> or SrZrO<sub>3</sub>) leading to degradation in cell performance. So there is a need to develop new cathode materials that will operate at low temperature with high reliability and chemical stability. Amongst others,  $A_2MO_{4+\delta}$ compounds with K<sub>2</sub>NiF<sub>4</sub> structure have recently been investigated as promising substitutes for LSM. Indeed, these materials are mixed ionic and electronic conductors (MIECs) that moreover exhibit rather high electrocatalytic properties. It could then be attempted to synthesize them as dense materials for SOFC cathodes. A specific

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attention was focused on lanthanum nickelate La<sub>2</sub>NiO<sub>4+ δ</sub> because it exhibits convenient electrochemical characteristics [1–5]. Its thermal expansion coefficient (TEC) is very close to those of the most commonly used electrolyte materials  $(13\cdot 10^{-6}~\text{K}^{-1}~\text{[2]}, 11.9\cdot 10^{-6}~\text{K}^{-1}$  and  $11.6\cdot 10^{-6}~\text{K}^{-1}$  for La<sub>2</sub>NiO<sub>4+ δ</sub>, CeO<sub>2</sub>–Gd<sub>2</sub>O<sub>3</sub> (CGO) and ZrO<sub>2</sub>–Y<sub>2</sub>O<sub>3</sub> (YSZ) respectively). Moreover, its TEC value is very close to the one recorded for ferritic steel interconnect materials  $(11.0\text{-}12.5\cdot 10^{-6}~\text{K}^{-1})$  [9] which are essential in the last generation metal supported SOFC stack. Its oxygen surface exchange coefficient (k) and oxygen diffusion coefficient (D\*) are interesting and seem much better than those of LSM and La<sub>1-x</sub>Sr<sub>x</sub>Co<sub>1-y</sub>Fe<sub>y</sub>O<sub>3</sub> (LSCF), the most commonly used cathodes (Table 1).

La $_2$ NiO $_4$  coatings have already been produced in our laboratory implementing conventional reactive magnetron sputtering [10]. In this study, we investigate the feasibility of producing thin and dense La $_2$ NiO $_{4+\delta}$  coatings as performed in the literature [11–13] by reactive magnetron sputtering under unstable conditions using Plasma Emission Monitoring (PEM) [14,15]. This technique is assumed to allow the deposition of oxide coatings with high sputtering rate. Four point probe electrical analyses were performed on annealed lanthanum nickelate films in static air at room temperature and in the temperature range from 293 to 1273 K every 25 K. On the one hand, measurements were carried out after 60 min stabilization in order to follow the effect of the asdeposited sample crystallization. On the other hand, the electrical conductivity is followed after 20 min stabilization for K $_2$ NiF $_4$  structure's samples.

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Table 1 Surface exchange (k) and oxygen diffusion coefficients  $(D^*)$  for different cathode materials.

	D* (700 °C)	k (700 °C)
La <sub>2</sub> NiO <sub>4</sub>	$3.4 \cdot 10^{-8}$ [2], $1.6 \cdot 10^{-8}$ [6],	$1.7 \cdot 10^{-7}$ [2], $1.3 \cdot 10^{-7}$ [6],
	$5.0 \cdot 10^{-8}$ [7]	$2.0 \cdot 10^{-6}$ [7]
LSM	$3.2 \cdot 10^{-16}$ [8]	$1.0 \cdot 10^{-9}$ [8]
LSCF	$3.2 \cdot 10^{-9}$ [7], $7.2 \cdot 10^{-9}$ [8]	$1.0 \cdot 10^{-7}$ [7], $6.1 \cdot 10^{-7}$ [8]

#### 2. Experimental details

#### 2.1. Deposition device

The experimental deposition device is a 100 L Alcatel SCM 650 sputtering chamber pumped down via a system combining XDS35i Dry Pump and a 5401CP turbo-molecular pump. The sputtering chamber is equipped with three 200 mm in diameter magnetron targets and with a 620 mm in diameter rotating substrate holder parallel to the targets at a distance of about 110 mm. The La and Ni targets were supplied with a pulsed DC Advanced Energy dual generator allowing the control of the discharge current. The discharge current was fixed at 2.5 A on the La target and was varied on the Ni target to obtain the convenient composition of the K<sub>2</sub>NiF<sub>4</sub> structure. The substrates were made of alumina and YSZ pellets as well as glass slides positioned on the substrate holder at 170 mm from its center point. Argon and oxygen flow rates were controlled with Brooks flowmeters and the pressure was measured using a MKS Baratron gauge. The deposition stage was monitored using a closed loop control PEM (Plasma Emission Monitoring) system relying on an optical emission spectroscopy device (OES) [15,16]. This technique is based on the measurement of the optical intensity of the 394.91 nm La emission line  $(I_{La}^*)$  emitted from a volume near the target. The signal is collected through an optical fiber and directed to a Ropper Scientific SpectraPro 500i spectrometer, with a 1200 groove mm<sup>-2</sup> grating and a photomultiplier tube (Hamamatsu R 636). Then, the information is transferred to a computer where a homemade software developed with Labview® monitors the oxygen flow rate to maintain the intensity of the optical signal  $I_{La}^*$  at a fixed value.

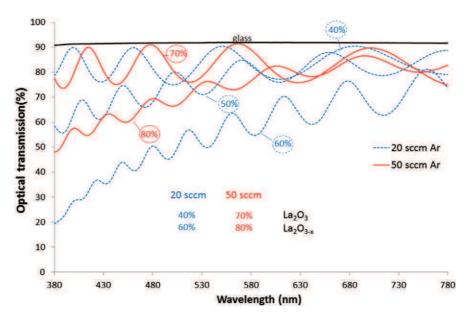
#### 2.2. Structural, morphological and optical characterizations

The morphology of the coatings was characterized by Scanning Electron Microscopy (SEM) using a JEOL JSM 5800 LV equipped with Energy Dispersive Spectroscopy (EDS) for chemical measurements. The structural features of the coatings were identified in Bragg–Brentano configuration X-ray diffraction using a BRUKER D8 focus diffractometer ( $CoK_{\alpha 1} + _{\alpha 2}$  radiations) equipped with the LynxEye linear detector. XRD patterns were collected at room temperature during 10 min in the [ $20^{\circ}$ – $80^{\circ}$ ] scattering angle range by steps of 0.019°. The coating thickness was determined using the "step" method (a small surface of the substrate is covered with a tape that is removed after deposition leaving a step due to the coating thickness) with an Altysurf profilometer from Altimet allowing an accuracy of about 20 nm. Before each measurement, the calibration of the experimental device was realized with a reference sample number 787569 accredited by CETIM, France.

The optical transmittance measurements were performed with a UV-visible-NIR Shimadzu UV-3600 Spectrophotometer controlled by UV probe 2.33 software. All measurements were carried out on glass substrates between 380 and 780 nm.

#### 2.3. Electrical measurements

The electrical resistivity measurements were performed with a HP 3458A multimeter on La-Ni-O films deposited on alumina substrates. With regard to its high insulating character, it is assumed in the following that the substrate has no significant contribution to the electrical conductivity. The four-point-probe technique with four Pt aligned electrodes was used. Two outer probes behaved as the current-carrying electrodes (I1, I2) and the two inner ones were used to measure the voltage (E1, E2). Two cell configurations were used for the measurements: cell 1 was used to define the resistivity at room temperature (Jandel, Linslade, UK). It is a standard and certified cell allowing the accurate determination of the geometric factor. The second cell developed by the LEPMI laboratory (Grenoble, France) allows measurements at various temperatures. The cell is placed inside an alumina tube and positioned into a furnace (Pekly, Thions Gardais, France). The comparison of the resistance measured at room temperature with cell 1 and cell 2 was used to determine the geometric factor of cell 2.



 $\textbf{Fig. 1.} \ \ \textbf{Optical transmission vs.} \ \ wavelength \ \ of \ La_2O_3 \ \ coatings \ \ deposited \ \ with \ 20 \ or \ 50 \ sccm \ Ar.$ 

#### 3. Result and discussion

#### 3.1. Determination of the optimal regulation setpoint

In DC or pulsed DC mode, the optical signal of the sputtered metal atoms  $I_M^*$  measured by OES in a pure Ar atmosphere varies as the square function of the discharge current [18,19]. When oxygen gas is introduced into the discharge, a hysteresis loop appears on the oxygen partial pressure versus oxygen flow rate curve related to the instability of the sputtering conditions. So, the transition between the fast metallic and the slow ceramic deposition rates occurs suddenly. The Plasma Emission Monitoring (PEM) system allows the deposition of oxide coatings in these unstable sputtering conditions by fixing the intensity of the plasma emission line of the metallic atoms sputtered from the target with a closed loop as previously detailed in [14]. Indeed, PEM is a very suitable technique to allow high growth rate of oxide coatings [14,20]. As the main element of La<sub>2</sub>NiO<sub>4</sub> is La, the PEM control was performed on the La target at a fixed 2.5 A discharge current in order to deposit coatings with high sputtering rate without consuming too much the target. In the first set of experiments, the optical emission signal collected in pure argon atmosphere was allocated to 100%. Then, the PEM setpoint  $I_{La}^*$  was varied from 30 to 80% in order to deposit transparent coatings.

Fig. 1 shows the evolution of the optical transmission of La-O coatings deposited at 2.5 A applied on the La target for various Ar flow rates and regulation setpoints. For coatings deposited with 20 sccm Ar flow rate, a regulation setpoint fixed at 40% produces an unattenuated optical signal, which reveals the transparency (low extinction coefficient k) of the coating. The optical signal value is between 75 and 90%, the latter value is similar to the one recorded for glass. Moreover, the optical transmission signal is more and more attenuated for higher setpoints. In a previous study dedicated to the optical emission spectroscopy study of the deposition of TiO<sub>2</sub> [16], it was shown that increasing the setpoint decreases the coating transparency and then the stoichiometry of the coating. Indeed, the sputtered flow of metal atoms increases with the setpoint, which was associated with a reduction of the oxygen partial pressure in the reactor. Higher Ar flow rate induces higher total pressure in the device and then theoretically less dense and more columnar coatings with lower deposition rate. Such behavior means that the La-O based film is fully oxidized for setpoints lower than 40% and sub-stoichiometric for higher setpoints. Indeed, as

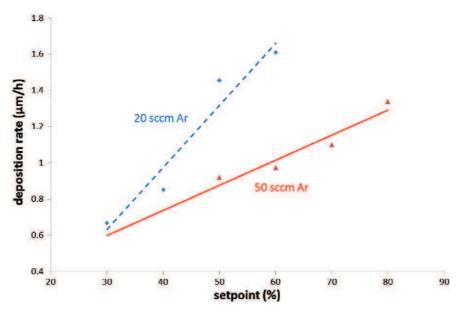
**Table 2**Main deposition conditions of the study.

	Ar flow rate $= 20 \text{ sccm}$	Ar flow rate = 50 sccm		
Total pressure (Pa)	0.30	0.44		
Setpoint (%)	50	70		
Oxygen flow rate (sccm)	5.5-6.2	4.5-4.9		
Run duration (h)	1 h 30 min-2 h	2 h-2 h 20 min		
Discharge current for La (A)	2.5	2.5		
Frequency (Hz) $-$ toff ( $\mu$ s)	50-5	50-5		
Discharge current for Ni (A)	0.25-0.45	0.55-0.65		
Frequency (Hz) $-$ toff ( $\mu$ s)	50-5	50-5		

shown by Briois et al. for YSZ coatings characterized by spectrophotometry and EPMA, transparent coatings are fully oxidized [21]. By increasing the Ar flow rate at 50 sccm, the transition between stoichiometric and under-stoichiometric oxide deposits appears at higher setpoints (i.e. 70%). The choice of the optimal setpoint must also be guided by the deposition rate of the coatings. Fig. 2 shows that the deposition rate is varying linearly with the setpoint values. A deposition rate around 0.65 µm/h is achieved at a setpoint of 30% whatever the Ar flow rate whereas if the setpoint is doubled it is of 1.6 and 0.9  $\mu m/h$ for 20 and 50 sccm, respectively. By increasing the Ar flow rate, the deposition rate becomes less sensitive to the variation of the regulation setpoint. A setpoint of 50% was then chosen for the 20 sccm Ar flow rate flow rate because it presents a good compromise between deposition rate and stoichiometry of the coating. In addition, the difference between the atomic radii of La (187 pm) and Ni atoms (124 pm) would probably lead during the deposition of the cathode layer to an amorphous coating because of the confusion principle. This phenomenon imposes the realization of a crystallization annealing treatment which may saturate the film. For higher Ar flow rate (i.e. 50 sccm), the differences between the deposition rates at 70% and 80% are not significant enough. So the coatings will be deposited with the conditions allowing the deposition of a transparent coating (i.e. 70% setpoint).

#### 3.2. Elaboration of La-Ni-O coatings

The experimental parameters for the synthesis of the films are summarized in Table 2. The coatings are deposited by the co-sputtering of La and Ni targets in  $Ar-O_2$  mixtures for which the oxygen flow rate is controlled by the PEM system. Fig. 3 presents the metallic La/Ni ratio



**Fig. 2.** Deposition rate of La<sub>2</sub>O<sub>3</sub> coatings as a function of  $I_{La}^*$  for 20 and 50 sccm Ar.

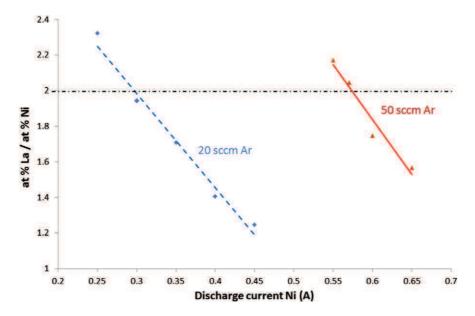


Fig. 3. Evolution of atomic composition ratio La/Ni measured by EDS as a function of current dissipated on the Ni target for different Ar flow rates (I<sub>La</sub> = 2.5 A).

determined by EDS analyses versus the discharge current applied to the Ni target while the La target current is fixed at 2.5 A. EDS measurement is sufficiently accurate to determine the cationic composition of thin films because this technique is well adapted to measure heavy elements as shown elsewhere [21]. For both Ar flow rates, the metallic ratio decreases linearly with the increase of the current. In addition, a higher current is needed to deposit the same metallic ratio at high Ar flow rate. To obtain the La<sub>2</sub>NiO<sub>4</sub> composition a current discharge of 0.3 and 0.57 A with 20 and 50 sccm Ar flow rates (1.94 and 2.04 La/Ni ratio) must be supplied, respectively. The linear evolution of the composition with the current applied on the Ni target reveals that the oxygen flow

rate is sufficient to deposit a ceramic instead of a metallic layer. The regulation ensures then a constant oxidation rate of the La target and subsequently a constant sputtering rate of the La atoms. As expected, XRD performed on as-deposited samples shows the presence of an amorphous structure whatever the composition. In order to crystallize the La<sub>2</sub>NiO<sub>4</sub> phase, different annealing temperatures (973 K–1273 K for 2 h) were tested in a previous study [22] with samples presenting that a La/Ni ratio of about 2. 1173 K for 2 h was found to be the optimal thermal treatment. It has to be noticed that these coatings are annealed at higher temperature than those deposited with stable sputtering conditions [10]. Fig. 4 presents the XRD patterns of annealed coatings

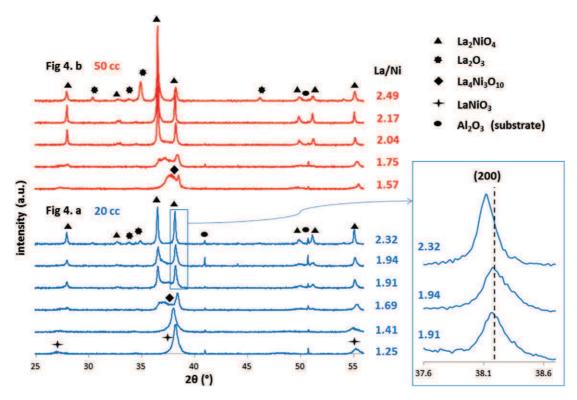


Fig. 4. XRD spectra as a function of La/Ni metallic ratio for 20 sccm and 50 sccm Ar flow rates after annealing at 1173 K for 2 h. JCPDS files: 00-033-0710, 00-050-0243, 01-071-1126, 01-089-3460.

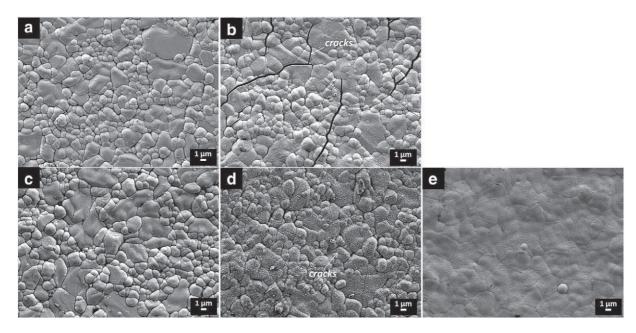


Fig. 5. SEM view of surface of samples deposited on alumina substrate with 20 sccm (a, b) and 50 sccm (c, d) Ar as-deposited (a, c) and annealed in air for 2 h at 1173 K (b, d) with La<sub>2</sub>NiO<sub>4</sub> structure. View of a coating deposited at 50 sccm Ar on YSZ after annealing (e).

elaborated at 20 (Fig. 4a) and 50 sccm (Fig. 4b) of Ar flow rates and various discharge currents, which means various atomic La/Ni ratios. The crystalline structure of the La–Ni–O coatings evolves with the metallic ratios. When the Ni content is high (La/Ni ratio below 1.5, see Fig. 4b), coatings crystallize mainly in the LaNiO $_3$  structure. By decreasing the Ni content (La/Ni ratio between 1.5 and 2), a mixture of phases is identified that includes LaNiO $_3$ , La $_4$ Ni $_3$ O $_{10}$  and La $_2$ NiO $_4$ , La $_2$ NiO $_4$  is the only phase identified for the coatings elaborated with ratios around 2 (1.91 and 1.94 at 20 sccm 2.04 and 2.17 at 50 sccm). For a La/Ni ratio superior to 2, the diffraction peaks are moved to the lowest angles, implying an increase of the lattice parameter due to an excess of La in which atomic radius is bigger than the Ni one. When La $_2$ NiO $_4$  phase is oxygen saturated, La $_2$ O $_3$  is crystallizing. These results are in agreement with the La–Ni–O phase diagram in air [23]. Same behavior is noticed for both Ar flow

rates studied in this work. However, increasing the Ar flow rate seems to enhance the crystallization but the coating appears to be oriented along the (113) crystallographic plane.

Morphological features were observed by SEM on the surfaces of the coatings (Fig. 5) and on the brittle-fracture cross sections (Fig. 6) of as-deposited and annealed coatings. The observation of the surface of the as-deposited films (Fig. 5a and c) reveals an adherent and covering film with a top morphology reproducing that of the alumina substrate. These coatings are then conformal. This observation is confirmed by the arithmetic roughness measurements (Ra) of the samples before and after deposits which are  $0.49\pm0.01~\mu m$  and  $0.51\pm0.01~\mu m$  respectively. The good adherence of these films is pointed out by the observation of the cross section of the films (Fig. 6) which also denotes a slightly columnar aspect. The thickness of these films is in

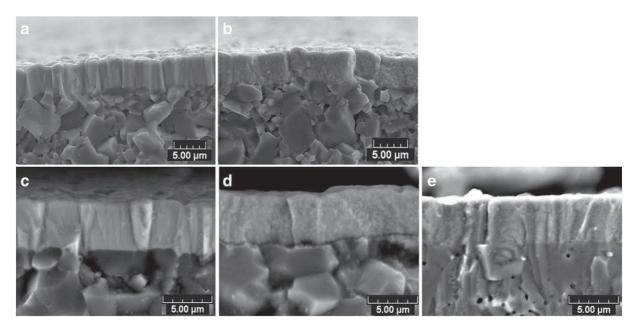


Fig. 6. Brittle fracture cross section of samples deposited with 20 sccm (a, b) and 50 sccm (c, d) Ar on alumina substrate as-deposited and annealed in air for 2 h at 1173 K with La<sub>2</sub>NiO<sub>4</sub> structure. Cross section of a coating deposited at 50 sccm Ar on YSZ after annealing (e).

good agreement with 3D measurements (i.e.  $\approx$  3.5  $\mu$ m). The crystallization thermal treatment allows the densification of the coatings (Fig. 6b and d) but some cracks appear on the surface (Fig. 5b and d). These cracks are more visible on the films deposited with an Ar flow rate of 20 sccm (Fig. 5b) than 50 sccm (Fig. 5d). Indeed, a lower pressure causes a higher coating density, which increases the mechanical strains due to the different thermal expansion coefficients between the film and the substrate during the annealing treatment at high temperature. Alumina TEC is much lower than the coating one, 7 and  $13 \cdot 10^{-6} \, \text{K}^{-1}$ respectively. Cracking of films could then happen during cooling. In order to check this hypothesis, films were synthesized on YSZ substrates (conventional material of SOFC electrolytes) in which TEC is around  $11 \cdot 10^{-6} \,\mathrm{K}^{-1}$ , closest to the coating one as compared to alumina. The surface and cross section observations after the thermal treatment for the coatings realized with Ar flow rate of 50 sccm show no cracks, which is favorable for the SOFC materials commonly used (Figs. 5e and 6e).

#### 3.3. Electrical analyses

In order to assess the effect of the crystallization on the sample conductivities, electrical measurements were performed implementing a four point probe method on as-deposited samples presenting a metallic ratio of about 2 as reported in Fig. 7. Changes in the resistance versus temperature curve slopes are clearly identified on this graph and involve structural, microstructural or chemical modifications of the films. The correlation with XRD measurements performed on the samples deposited with 50 sccm Ar after annealing at increasing temperatures [22] shows that amorphous coatings are highly resistive and that the coating resistance decreases with its crystallization. During the increase in temperature, different crystallographic phases appear. La<sub>2</sub>O<sub>3</sub> and La<sub>4</sub>Ni<sub>3</sub>O<sub>10</sub> orthorombic phases are the first phases to crystallize. La<sub>2</sub>NiO<sub>4</sub> tetragonal phase starts to crystallize from 1123 K [22]. Moreover, the crystallization seems to occur at lower temperature for the sample deposited with 50 sccm of Ar flow rate.

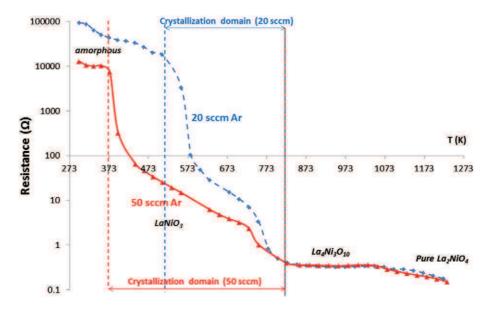
In order to determine the characteristics of the well-crystallized films, samples were annealed at 1173 K for 2 h under air before performing the electrical measurements. The resistivity of the annealed coatings as a function of their La/Ni ratio at room temperature (286 K) and after 20 min stabilization at 973 K is reported in Table 3. The increase of the Ni content in the samples permits to obtain the highest

**Table 3**Resistivity of La–Ni–O crystallized samples with different Ar flow rates.

Ar flow rate		Samples' conductivity at room temperature and at 700 °C (S·cm)  La/Ni ratio								
										1.25
		20 sccm	293 K	275.5	116.2		10.9		2.3	
	973 K	295.0	157.7		45.4		43.5		27.5	
50 sccm	293 K			144.0		16.2		2.2		0.06
	973 K			292.3		62.3		52.2		22.1

conductivities. As expected, the most favorable behavior is obtained for the samples which crystallized mainly as a perovskite LaNiO $_3$  structure. However the La $_2$ NiO $_4$  structure presents reasonable conductivities. For the same metallic ratios and also the same structure (La/Ni = 1.69–1.75 and 1.95–2.04), the electrical conductivity of the samples deposited with 50 sccm Ar is higher than with 20 sccm at 973 K. This difference is certainly due to the presence of cracks on the surface of the samples deposited with 20 sccm Ar. There is probably no effect of the density of the coatings because the four point probe technique takes place only on the surface of the samples and not through its thickness.

Samples with a La/Ni ratio of about 2, which means a La<sub>2</sub>NiO<sub>4</sub> structure after annealing 2 h at 1173 K, were especially studied from 293 to 1273 K after 20 min stabilization at each temperature (Fig. 8). The conductivity of these samples increases with temperature and tends to be stabilized over 773 K. The electrical behavior of the corresponding bulk materials is quite different. The conductivity of these samples increases up to a temperature around 773 K and decreases at higher temperatures. This diminution is explained by an oxygen loss in the structure of the bulk materials [2,3,17]. Consequently, it could be assumed that oxygen stoichiometry of thin layers seems to be less sensitive to temperature. Fig. 8 highlights that the electrical conductivity of the films (30–60 S·cm) is in the same order of magnitude than the one of bulk materials in SOFC application domain. As explained before, samples deposited with 20 sccm and 50 sccm Ar flow rates present different conductivities certainly induced by the presence of cracks but their different crystallographic orientations may also assume a role in their electrical behavior. Electrical tests were also repeated for several cycles during the heating and the cooling stages of the sample deposited



 $\textbf{Fig. 7.} \ Resistance \ of \ as \ deposited \ coatings \ of \ La_2NiO_4 \ composition \ deposited \ with \ 20 \ sccm \ (La:Ni = 1.94) \ or \ 50 \ sccm \ Ar \ (La/Ni = 2.04) \ as \ a \ function \ of \ the \ annealing \ temperature.$ 

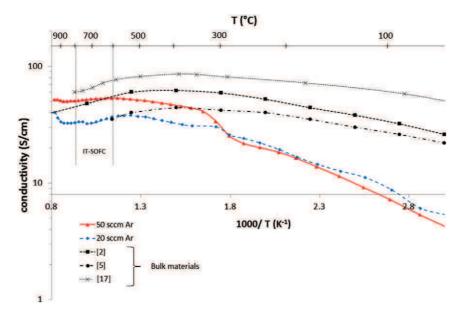


Fig. 8. Conductivity of coatings of various composition deposited with 20 sccm Ar and 50 sccm Ar previously annealed at 1173 K for 2 h measured as a function of annealing temperature.

with 50 sccm Ar flow rate. All the tests showed the same electrical behavior with quite the same electrical conductivity values.

#### 5. Conclusion

La-Ni-O coatings were deposited by magnetron sputtering on different substrates by co-sputtering of La and Ni metallic targets in the presence of reactive argon-oxygen mixture gas. The use of a closed loop control which consists of controlling the introduced reactive gas flow rate in order to fix the system in unstable sputtering domain allows obtaining optimal deposition rates under chosen operational conditions. As-deposited coatings with La/Ni ratios of about 2 are amorphous and crystallize under a tetragonal La2NiO4 phase after an annealing treatment at 1173 K for 2 h under air. A higher Ar flow rate, i.e. a higher pressure, coupled with a lower setpoint allows minimizing the crack formation during the treatments and leading thus to a higher electrical conductivity. La<sub>2</sub>NiO<sub>4</sub> coatings present an electrical conductivity of 30-60 S·cm in the temperature range for intermediate temperature solid oxide fuel cells (873-1073 K). These values are in the same order of magnitude than the values reported for bulk samples in the literature.

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